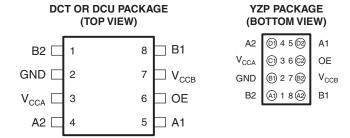
# 2-BIT BIDIRECTIONAL VOLTAGE-LEVEL TRANSLATOR FOR OPEN-DRAIN AND PUSH-PULL APPLICATIONS

#### **FEATURES**

- No Direction-Control Signal Needed
- Max Data Rates
  - 24 Mbps (Push Pull)
  - 2 Mbps (Open Drain)
- Available in the Texas Instruments NanoFree™ Package
- 1.65 V to 3.6 V on A port and 2.3 V to 5.5 V on B port (V<sub>CCA</sub> ≤ V<sub>CCB</sub>)
- V<sub>CC</sub> Isolation Feature If Either V<sub>CC</sub> Input Is at GND, Both Ports Are in the High-Impedance State
- No Power-Supply Sequencing Required Either V<sub>CCA</sub> or V<sub>CCB</sub> Can Be Ramped First
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

- ESD Protection Exceeds JESD 22
  - A Port
    - 2500-V Human-Body Model (A114-B)
    - 250-V Machine Model (A115-A)
    - 1500-V Charged-Device Model (C101)
  - B Port
    - 8-kV Human-Body Model (A114-B)
    - 250-V Machine Model (A115-A)
    - 1500-V Charged-Device Model (C101)



#### **DESCRIPTION/ORDERING INFORMATION**

This two-bit noninverting translator uses two separate configurable power-supply rails. The A port is designed to track  $V_{CCA}$ .  $V_{CCA}$  accepts any supply voltage from 1.65 V to 3.6 V. The B port is designed to track  $V_{CCB}$ .  $V_{CCB}$  must be less than or equal to  $V_{CCB}$ .  $V_{CCB}$  accepts any supply voltage from 2.3 V to 5.5 V. This allows for low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

When the output-enable (OE) input is low, all outputs are placed in the high-impedance state.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING(3)
	NanoStar™ - WCSP (DSBGA) 0.23-mm Large Bump - YZP	Reel of 3000	TXS0102YZPR	2H_
-40°C to 85°C	SSOP - DCT	Reel of 3000	TXS0102DCTR	NFEZ
	550F	Tube of 250	TXS0102DCTT	NFEZ
	VSSOP - DCU	Reel of 3000	TXS0102DCUR	NFE_

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (3) DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



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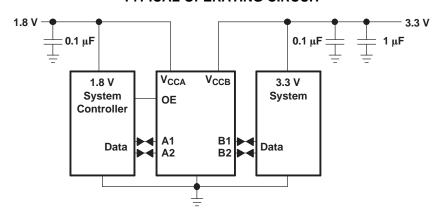
NanoFree is a trademark of Texas Instruments.



## PIN DESCRIPTION (DCT AND DCU PACKAGES)

NO.	NAME	FUNCTION
1	B2	Input/output B. Referenced to V <sub>CCB</sub> .
2	GND	Ground
3	$V_{CCA}$	A-port supply voltage. 1.65 V $\leq$ V <sub>CCA</sub> $\leq$ 3.6 V and V <sub>CCA</sub> $\leq$ V <sub>CCB</sub>
4	A2	Input/output A. Referenced to V <sub>CCA</sub> .
5	A1	Input/output A. Referenced to V <sub>CCA</sub> .
6	OE	3-state output mode enable. Pull OE low to place all outputs in 3-state mode. Referenced to $V_{\text{CCA}}$ .
7	$V_{CCB}$	B-port supply voltage. 2.3 V ≤ V <sub>CCB</sub> ≤ 5.5 V
8	B1	Input/output B. Referenced to V <sub>CCB</sub> .

#### **TYPICAL OPERATING CIRCUIT**



#### ABSOLUTE MAXIMUM RATINGS(1)

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CCA}$	Supply voltage range		-0.5	4.6	V
$V_{CCB}$	Supply voltage range		-0.5	6.5	V
V	Input voltage range (2)	A port	-0.5	4.6	V
VI	Input voltage range (2)	B port	-0.5	6.5	V
V	Voltage range applied to any output	A port	-0.5	4.6	V
Vo	in the high-impedance or power-off state <sup>(2)</sup>	B port	-0.5	6.5	V
V	Valta and an analysis of the state of the state of (2) (3)	A port	-0.5	$V_{CCA} + 0.5$	V
Vo	Voltage range applied to any output in the high or low state (2)(3)	B port	-0.5	$V_{CCB} + 0.5$	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
lo	Continuous output current			±50	mA
	Continuous current through V <sub>CCA</sub> , V <sub>CCB</sub> , or GND			±100	mA
		DCT package		220	
$\theta_{JA}$	Package thermal impedance (4)	DCU package		227	°C/W
		YZP package		102	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V<sub>CCA</sub> and V<sub>CCB</sub> are provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

#### RECOMMENDED OPERATING CONDITIONS(1)(2)

			V <sub>CCA</sub>	V <sub>CCB</sub>	MIN	MAX	UNIT
$V_{CCA}$	Supply				1.65	3.6	V
$V_{CCB}$	voltage (3)				2.3	5.5	V
		A-port I/Os	1.65 V to 1.95 V	2.3 V to 5.5 V	V <sub>CCI</sub> - 0.2	V <sub>CCI</sub>	
\/	High-level	A-port I/Os	2.3 V to 3.6 V	2.3 V to 3.3 V	$V_{CCI} - 0.4$	$V_{CCI}$	V
V <sub>IH</sub>	input voltage	B-port I/Os	1.65 V to 3.6 V	2.3 V to 5.5 V	$V_{\rm CCI} - 0.4$	$V_{CCI}$	V
		OE input	1.05 V 10 3.6 V	2.3 V 10 5.5 V	$V_{CCA} \times 0.65$	5.5	
		A-port I/Os			0	0.15	
$V_{IL}$	Low-level input voltage	B-port I/Os	1.65 V to 3.6 V	2.3 V to 5.5 V	0	0.15	V
	mpat voltago	OE input			0	$V_{CCA} \times 0.35$	
		A-port I/Os, push-pull driving				10	
$\Delta t/\Delta v$	Input transition rise or fall rate	B-port I/Os, push-pull driving	1.65 V to 3.6 V	2.3 V to 5.5 V		10	ns/V
	nee en idii idie	Control input				10	
T <sub>A</sub>	Operating free-a	air temperature			-40	85	°C

<sup>(1)</sup> V<sub>CCI</sub> is the supply voltage associated with the input port.

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<sup>(2)</sup> V<sub>CCO</sub> is the supply voltage associated with the output port.

<sup>(3)</sup>  $V_{CCA}$  must be less than or equal to  $V_{CCB}$ , and  $V_{CCA}$  must not exceed 3.6 V.



### ELECTRICAL CHARACTERISTICS (1)(2)(3)

over recommended operating free-air temperature range (unless otherwise noted)

	DAMETED	TEST	W	V	T <sub>A</sub> =	= 25°(	2	-40°C to 85	5°C	UNIT
Ρ,	ARAMETER	CONDITIONS	V <sub>CCA</sub>	V <sub>CCB</sub>	MIN 7	TYP	MAX	MIN	MAX	UNII
$V_{OHA}$		$I_{OH} = -20 \mu A,$ $V_{IB} \ge V_{CCB} - 0.4 V$	1.65 V to 3.6 V	2.3 V to 5.5 V				V <sub>CCA</sub> × 0.67		V
V <sub>OLA</sub>		$I_{OL} = 1 \text{ mA},$ $V_{IB} \le 0.15 \text{ V}$	1.65 V to 3.6 V	2.3 V to 5.5 V					0.4	V
V <sub>OHB</sub>		$I_{OH} = -20 \mu A,$ $V_{IA} \ge V_{CCA} - 0.2 V$	1.65 V to 3.6 V	2.3 V to 5.5 V				V <sub>CCB</sub> × 0.67		V
V <sub>OLB</sub>		$I_{OL} = 1 \text{ mA},$ $V_{IA} \le 0.15 \text{ V}$	1.65 V to 3.6 V	2.3 V to 5.5 V					0.4	V
II	OE		1.65 V to 3.6 V	2.3 V to 5.5 V			±1		±2	μΑ
	A port		0 V	0 to 5.5 V			±1		±2	μΑ
I <sub>off</sub>	B port		0 to 3.6 V	0 V			±1		±2	μΑ
l <sub>OZ</sub>	A or B port		1.65 V to 3.6 V	2.3 V to 5.5 V			±1		±2	μΑ
			1.65 V to V <sub>CCB</sub>	2.3 V to 5.5 V					2.4	
$I_{CCA}$		$V_I = V_O = \text{open},$ $I_O = 0$	3.6 V	0 V					2.2	μΑ
		10 – 3	0 V	5.5 V					-1	
			1.65 V to V <sub>CCB</sub>	2.3 V to 5.5 V					12	
$I_{CCB}$		$V_I = V_O = \text{open},$ $I_O = 0$	3.6 V	0 V					-1	μΑ
		10 – 3	0 V	5.5 V					1	
I <sub>CCA</sub> +	· I <sub>CCB</sub>	$V_I = V_{CCI}$ or GND, $I_O = 0$	1.65 V to V <sub>CCB</sub>	2.3 V to 5.5 V					14.4	μΑ
CI	OE		3.3 V	3.3 V		2.5			3.5	pF
	A or B port		3.3 V	3.3 V		10				
Cio	A port					5		6		pF
	B port					6		7.5		

 $<sup>\</sup>begin{array}{ll} \hbox{(1)} & V_{CCI} \text{ is the $V_{CC}$ associated with the input port.} \\ \hbox{(2)} & V_{CCO} \text{ is the $V_{CC}$ associated with the output port.} \\ \hbox{(3)} & V_{CCA} \text{ must be less than or equal to $V_{CCB}$, and $V_{CCA}$ must not exceed 3.6 V.} \\ \end{array}$ 

#### **TIMING REQUIREMENTS**

over recommended operating free-air temperature range,  $V_{CCA}$  = 1.8 V ± 0.15 V (unless otherwise noted)

					$V_{CCB} = 2.5 \text{ V}$ $V_{CC} = 3.3 \text{ V}$ $V_{CC} = 5 \text{ V}$ $\pm 0.2 \text{ V}$ $\pm 0.5 \text{ V}$		UNIT			
				MIN	MAX	MIN	MAX	MIN	MAX	
	Data sata	Push-pull driving			21		22		24	Maria
	Data rate	Open-drain driving			2		2		2	Mbp
t <sub>w</sub>	Pulse	Push-pull driving	Data innuta	47		45		41		
	duration	Open-drain driving	Data inputs	500		500		500		ns

#### **TIMING REQUIREMENTS**

over recommended operating free-air temperature range,  $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (unless otherwise noted)

				V <sub>CCB</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 3. ± 0.3		V <sub>CC</sub> = ± 0.5		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	
	Data rate	Push-pull driving			20		22		24	Mbs
	Data Tate	Open-drain driving			2		2		2	Mbp
t <sub>w</sub>	Pulse	Push-pull driving	Data innuta	50		45		41		
	duration	Open-drain driving	Data inputs	500		500		500		ns

#### **TIMING REQUIREMENTS**

over recommended operating free-air temperature range,  $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$  (unless otherwise noted)

				V <sub>CC</sub> = 3.3 ± 0.3 V	3 V	V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
				MIN	MAX	MIN	MAX	
	Data rate	Push-pull driving			23		24	Mbps
	Data fate	Open-drain driving			2		2	ivibps
t <sub>w</sub>	Pulse duration	Push-pull driving	Data inputa	43		41		20
	Pulse duration	Open-drain driving	Data inputs	500		500		ns

Product Folder Link(s): TXS0102



#### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$  (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V <sub>CCB</sub> = ± 0.2		V <sub>CCB</sub> \ ± 0.	1	V <sub>CCB</sub> ± 0.		UNIT
	, ,	,		MIN	MAX	MIN	MAX	MIN	MAX	
			Push-pull driving		5.3		5.4		6.8	
t <sub>PHL</sub>	Α	В	Open-drain driving	2.3	8.8	2.4	9.6	2.6	10	ns
	A	Б	Push-pull driving		6.8		7.1		7.5	115
t <sub>PLH</sub>			Open-drain driving	45	260	36	208	27	198	
			Push-pull driving		4.4		4.5		4.7	
t <sub>PHL</sub>	В	^	Open-drain driving	1.9	5.3	1.1	4.4	1.2	4	20
	Ь	Α	Push-pull driving		5.3		4.5		0.5	ns
t <sub>PLH</sub>			Open-drain driving	45	175	36	140	27	102	
t <sub>en</sub>	OE	A or B			200		200		200	ns
t <sub>dis</sub>	OE	A or B			50		40		35	ns
	A martir	ioo timo	Push-pull driving	3.2	9.5	2.3	9.3	2	7.6	20
t <sub>rA</sub>	A-port r	ise time	Open-drain driving	38	165	30	132	22	95	ns
4	D nort r	ioo timo	Push-pull driving	4	10.8	2.7	9.1	2.7	7.6	20
t <sub>rB</sub>	B-port r	ise time	Open-drain driving	34	145	23	106	10	58	ns
	A nort f	all time	Push-pull driving	2	5.9	1.9	6	1.7	13.3	
t <sub>fA</sub>	A-port f	all time	Open-drain driving	4.4	6.9	4.3	6.4	4.2	6.1	20
	D now f	all time	Push-pull driving	2.9	13.8	2.8	16.2	2.8	16.2	ns
t <sub>fB</sub>	B-port f	an ume	Open-drain driving	6.9	13.8	7.5	16.2	7	16.2	
t <sub>SK(O)</sub>	Channel-to-c	hannel skew			0.7		0.7		0.7	ns
Max data rate			Push-pull driving	21		22		24		Mhna
iviax uata rate			Open-drain driving	2		2		2		Mbps

#### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$  (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V <sub>CCB</sub>	= 2.5 / 2 V	V <sub>CCB</sub> = ± 0.		V <sub>CCB</sub> ± 0.	= 5 V 5 V	UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	
			Push-pull driving		3.2		3.7		3.8	
t <sub>PHL</sub>	Α	В	Open-drain driving	1.7	6.3	2	6	2.1	5.8	
	A	В	Push-pull driving		3.5		4.1		4.4	ns
t <sub>PLH</sub>			Open-drain driving	43	250	36	206	27	190	
			Push-pull driving		3		3.6		4.3	
t <sub>PHL</sub>	В	^	Open-drain driving	1.8	4.7	2.6	4.2	1.2	4	
	Б	Α	Push-pull driving		2.5		1.6		1	ns
t <sub>PLH</sub>			Open-drain driving	44	170	37	140	27	103	
t <sub>en</sub>	OE	A or B			200		200		200	ns
t <sub>dis</sub>	OE	A or B			50		40		35	ns
	A 2011	ing time	Push-pull driving	2.8	7.4	2.6	6.6	1.8	5.6	
t <sub>rA</sub>	A-port r	ise time	Open-drain driving	34	149	28	121	24	89	ns
	B-port ri	iaa tima	Push-pull driving	3.2	8.3	2.9	7.2	2.4	6.1	no
t <sub>rB</sub>	Б-роп п	ise time	Open-drain driving	35	151	24	112	12	64	ns
	A nort f	iall time	Push-pull driving	1.9	5.7	1.9	5.5	1.8	5.3	
t <sub>fA</sub>	A-port f	all lime	Open-drain driving	4.4	6.9	4.3	6.2	4.2	5.8	ns
	D nort f	iall time	Push-pull driving	2.2	7.8	2.4	6.7	2.6	6.6	
t <sub>fB</sub>	B-port f	an unie	Open-drain driving	5.1	8.8	5.4	9.4	5.4	10.4	ns
t <sub>SK(O)</sub>	Channel-to-c	hannel skew			0.7		0.7		0.7	ns
May data rata			Push-pull driving	20		22		24		Mhna
Max data rate			Open-drain driving	2		2		2		Mbps



#### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range,  $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$  (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V <sub>CCB</sub> = ± 0.3		V <sub>CCB</sub> ± 0.	= 5 V 5 V	UNIT
	(INPUT)	(001701)	CONDITIONS	MIN	MAX	MIN	MAX	
4			Push-pull driving		2.4		3.1	
t <sub>PHL</sub>	Α	В	Open-drain driving	1.3	4.2	1.4	4.6	ns
+	A	Б	Push-pull driving		4.2		4.4	115
t <sub>PLH</sub>			Open-drain driving	36	204	28	165	
			Push-pull driving		2.5		3.3	
t <sub>PHL</sub>	В	A	Open-drain driving	1	124	1	97	ns
4	Ь	A	Push-pull driving		2.5		2.6	115
t <sub>PLH</sub>			Open-drain driving	3	139	3	105	
t <sub>en</sub>	OE	A or B			200		200	ns
t <sub>dis</sub>	OE	A or B			40		35	ns
<b>+</b> .	A port	rise time	Push-pull driving	2.3	5.6	1.9	4.8	ns
t <sub>rA</sub>	A-port	rise unie	Open-drain driving	25	116	19	85	115
•	B port	rise time	Push-pull driving	2.5	6.4	2.1	7.4	ns
t <sub>rB</sub>	Б-роп	nise unie	Open-drain driving	26	116	14	72	113
<b>+</b>	Λ port	fall time	Push-pull driving	2	5.4	1.9	5	ns
t <sub>fA</sub>	А-роп	iaii tiirie	Open-drain driving	4.3	6.1	4.2	5.7	115
t <sub>fB</sub>	P port	fall time	Push-pull driving	2.3	7.4	2.4	7.6	ns
чfВ	Б-роп	iaii tiirie	Open-drain driving	5	7.6	4.8	8.3	115
t <sub>SK(O)</sub>	Channel-to-	channel skew			0.7		0.7	ns
Max data rate			Push-pull driving	23		24		Mbps
iviax uala fale			Open-drain driving	2		2		wiphs

#### PRINCIPLES OF OPERATION

#### **Applications**

The TXS0102 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The TXS0102 is ideal for use in applications where an open-drain driver is connected to the data I/Os. The TXS0102 can also be used in applications where a push-pull driver is connected to the data I/Os, but the TXB0102 might be a better option for such push-pull applications.

#### **Architecture**

The TXS0102 architecture (see Figure 1) does not require a direction-control signal to control the direction of data flow from A to B or from B to A.

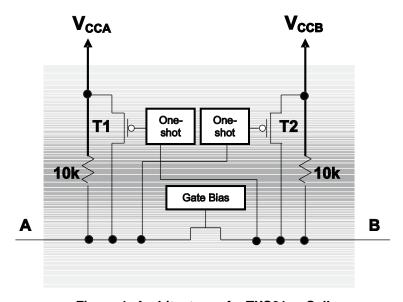


Figure 1. Architecture of a TXS01xx Cell

Each A-port I/O has an internal  $10-k\Omega$  pullup resistor to  $V_{CCA}$ , and each B-port I/O has an internal  $10-k\Omega$  pullup resistor to  $V_{CCB}$ . The output one-shots detect rising edges on the A or B ports. During a rising edge, the one-shot turns on the PMOS transistors (T1,T2) for a short duration, which speeds up the low-to-high transition.

#### **Input Driver Requirements**

The fall time ( $t_{fA}$ ,  $t_{fB}$ ) of a signal depends on the output impedance of the external device driving the data I/Os of the TXS0102. Similarly, the  $t_{PHL}$  and max data rates also depend on the output impedance of the external driver. The values for  $t_{fA}$ ,  $t_{fB}$ ,  $t_{PHL}$ , and maximum data rates in the data sheet assume that the output impedance of the external driver is less than 50  $\Omega$ .

#### **Power Up**

During operation, ensure that  $V_{CCA} \le V_{CCB}$  at all times. During power-up sequencing,  $V_{CCA} \ge V_{CCB}$  does not damage the device, so any power supply can be ramped up first.

#### **Enable and Disable**

The TXS0102 has an OE input that is used to disable the device by setting OE low, which places all I/Os in the Hi-Z state. The disable time  $(t_{dis})$  indicates the delay between the time when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time  $(t_{en})$  indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

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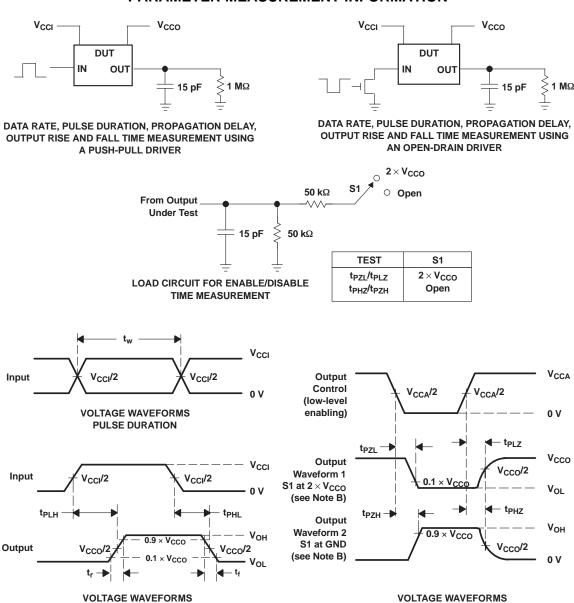


#### Pullup or Pulldown Resistors on I/O Lines

Each A-port I/O has an internal 10-k $\Omega$  pullup resistor to  $V_{CCA}$ , and each B-port I/O has an internal 10-k $\Omega$  pullup resistor to  $V_{CCB}$ . If a smaller value of pullup resistor is required, an external resistor must be added from the I/O to  $V_{CCA}$  or  $V_{CCB}$  (in parallel with the internal 10-k $\Omega$  resistors).



#### PARAMETER MEASUREMENT INFORMATION



- A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \Omega$ ,  $dv/dt \geq 1 V/ns$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
- H.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
- I.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

**PROPAGATION DELAY TIMES** 

J. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

**ENABLE AND DISABLE TIMES** 

#### PACKAGE OPTION ADDENDUM





#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp (3)
TXS0102DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCTT	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCTTE4	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCTTG4	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TXS0102YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
TXS0102YZTR	ACTIVE	DSBGA	YZT	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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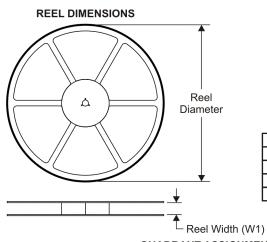
### **PACKAGE OPTION ADDENDUM**

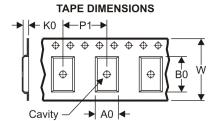
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#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

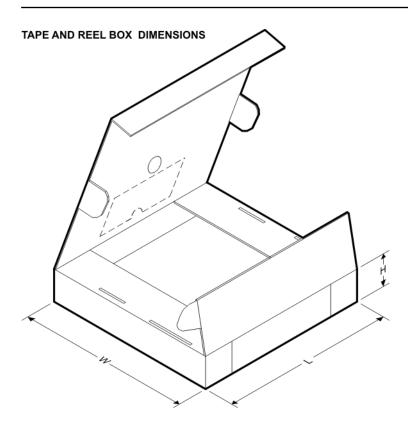
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXS0102DCUR	US8	DCU	8	3000	180.0	9.2	2.25	3.35	1.05	4.0	8.0	Q3
TXS0102YZPR	DSBGA	YZP	8	3000	180.0	8.4	1.1	2.1	0.56	4.0	8.0	Q1
TXS0102YZTR	DSBGA	YZT	8	3000	180.0	8.4	1.02	2.02	0.75	4.0	8.0	Q1



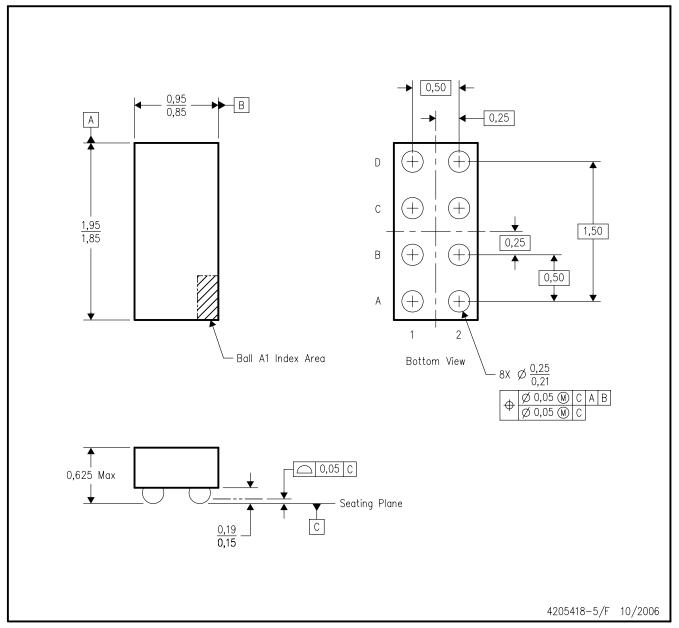


\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXS0102DCUR	US8	DCU	8	3000	202.0	201.0	28.0
TXS0102YZPR	DSBGA	YZP	8	3000	220.0	220.0	34.0
TXS0102YZTR	DSBGA	YZT	8	3000	220.0	220.0	34.0

## YZT (R-XBGA-N8)

### DIE-SIZE BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
  D. This package is Lead-free. Refer to the 8 YET package (drawing 4205421) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



## DCU (R-PDSO-G8)

### PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- : A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-187 variation CA.



#### DCT (R-PDSO-G8)

#### PLASTIC SMALL-OUTLINE PACKAGE

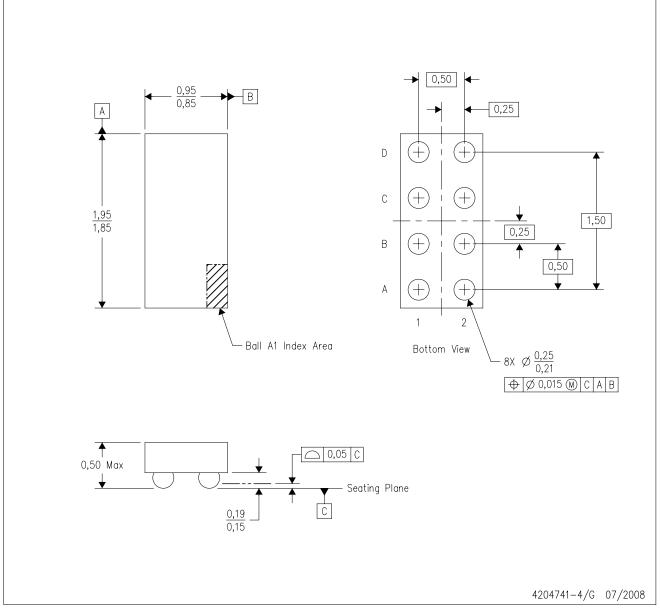


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion
- D. Falls within JEDEC MO-187 variation DA.

YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree  $^{\text{TM}}$  package configuration.
- D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

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